

## General Description

The AO7407 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications.

## Features

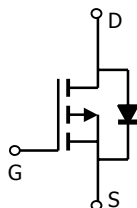
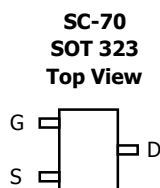
$$V_{DS} (V) = -20V$$

$$I_D = -1.2 A$$

$$R_{DS(ON)} < 135m\Omega (V_{GS} = -4.5V)$$

$$R_{DS(ON)} < 170m\Omega (V_{GS} = -2.5V)$$

$$R_{DS(ON)} < 220m\Omega (V_{GS} = -1.8V)$$



### Absolute Maximum Ratings $T_A=25^\circ\text{C}$ unless otherwise noted

| Parameter                              | Symbol                 | Maximum    | Units            |
|--|------------------------|------------|------------------|
| Drain-Source Voltage                   | $V_{DS}$               | -20        | V                |
| Gate-Source Voltage                    | $V_{GS}$               | $\pm 8$    | V                |
| Continuous Drain Current <sup>A</sup>  | $T_A=25^\circ\text{C}$ | -1.2       | A                |
|  | $T_A=70^\circ\text{C}$ | -1.0       |                  |
| Pulsed Drain Current <sup>B</sup>      | $I_{DM}$               | -10        |                  |
| Power Dissipation <sup>A</sup>         | $T_A=25^\circ\text{C}$ | 0.35       | W                |
|  | $T_A=70^\circ\text{C}$ | 0.22       |                  |
| Junction and Storage Temperature Range | $T_J, T_{STG}$         | -55 to 150 | $^\circ\text{C}$ |

### Thermal Characteristics

| Parameter                                | Symbol          | Typ          | Max | Units              |
|--|-----------------|--------------|-----|--------------------|
| Maximum Junction-to-Ambient <sup>A</sup> | $R_{\theta JA}$ | 300          | 360 | $^\circ\text{C/W}$ |
| Maximum Junction-to-Ambient <sup>A</sup> |                 | Steady-State | 350 |                    |
| Maximum Junction-to-Lead <sup>C</sup>    | $R_{\theta JL}$ | 280          | 320 | $^\circ\text{C/W}$ |

Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)

| Symbol                      | Parameter                             | Conditions  | Min  | Typ        | Max        | Units |
|-----------------------------|---------------------------------------|---|------|------------|------------|-------|
| <b>STATIC PARAMETERS</b>    |                                       |   |      |            |            |       |
| BV <sub>DSS</sub>           | Drain-Source Breakdown Voltage        | I <sub>D</sub> =-250μA, V <sub>GS</sub> =0V   | -20  |            |            | V     |
| I <sub>DSS</sub>            | Zero Gate Voltage Drain Current       | V <sub>DS</sub> =-16V, V <sub>GS</sub> =0V<br>T <sub>J</sub> =55°C                          |      |            | -1<br>-5   | μA    |
| I <sub>GSS</sub>            | Gate-Body leakage current             | V <sub>DS</sub> =0V, V <sub>GS</sub> =±8V   |      |            | ±100       | nA    |
| V <sub>GS(th)</sub>         | Gate Threshold Voltage                | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA                                   | -0.3 | -0.55      | -1         | V     |
| I <sub>D(ON)</sub>          | On state drain current                | V <sub>GS</sub> =-4.5V, V <sub>DS</sub> =-5V  | -10  |            |            | A     |
| R <sub>DS(ON)</sub>         | Static Drain-Source On-Resistance     | V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-1.2A<br>T <sub>J</sub> =125°C                      |      | 111<br>141 | 135<br>175 | mΩ    |
|                             |                                       | V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-1A   |      | 137        | 170        | mΩ    |
|                             |                                       | V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-1A   |      | 169        | 220        | mΩ    |
| g <sub>FS</sub>             | Forward Transconductance              | V <sub>DS</sub> =-5V, I <sub>D</sub> =-3A   | 4    | 7          |            | S     |
| V <sub>SD</sub>             | Diode Forward Voltage                 | I <sub>S</sub> =-1A, V <sub>GS</sub> =0V  |      | -0.78      | -1         | V     |
| I <sub>S</sub>              | Maximum Body-Diode Continuous Current |   |      |            | -0.6       | A     |
| <b>DYNAMIC PARAMETERS</b>   |                                       |   |      |            |            |       |
| C <sub>iss</sub>            | Input Capacitance                     | V <sub>GS</sub> =0V, V <sub>DS</sub> =-10V, f=1MHz  |      | 540        |            | pF    |
| C <sub>oss</sub>            | Output Capacitance                    |   |      | 72         |            | pF    |
| C <sub>rss</sub>            | Reverse Transfer Capacitance          |   |      | 49         |            | pF    |
| R <sub>g</sub>              | Gate resistance                       | V <sub>GS</sub> =0V, V <sub>DS</sub> =0V, f=1MHz  |      | 12         |            | Ω     |
| <b>SWITCHING PARAMETERS</b> |                                       |   |      |            |            |       |
| Q <sub>g</sub>              | Total Gate Charge                     | V <sub>GS</sub> =-4.5V, V <sub>DS</sub> =-10V, I <sub>D</sub> =-1A                          |      | 6.2        |            | nC    |
| Q <sub>gs</sub>             | Gate Source Charge                    |   |      | 0.54       |            | nC    |
| Q <sub>gd</sub>             | Gate Drain Charge                     |   |      | 1.44       |            | nC    |
| t <sub>D(on)</sub>          | Turn-On DelayTime                     | V <sub>GS</sub> =-4.5V, V <sub>DS</sub> =-10V, R <sub>L</sub> =15Ω,<br>R <sub>GEN</sub> =3Ω |      | 12         |            | ns    |
| t <sub>r</sub>              | Turn-On Rise Time                     |   |      | 10.7       |            | ns    |
| t <sub>D(off)</sub>         | Turn-Off DelayTime                    |   |      | 74         |            | ns    |
| t <sub>f</sub>              | Turn-Off Fall Time                    |   |      | 28.7       |            | ns    |
| t <sub>rr</sub>             | Body Diode Reverse Recovery Time      | I <sub>F</sub> =-1A, dI/dt=100A/μs  |      | 24.5       |            | ns    |
| Q <sub>rr</sub>             | Body Diode Reverse Recovery Charge    | I <sub>F</sub> =-1A, dI/dt=100A/μs  |      | 17.4       |            | nC    |

A: The value of R<sub>θJA</sub> is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with T<sub>A</sub>=25°C. The value in any a given application depends on the user's specific board design. The current rating is based on the t≤ 10s thermal resistance rating.

B: Repetitive rating, pulse width limited by junction temperature.

C. The R<sub>θJA</sub> is the sum of the thermal impedance from junction to lead R<sub>θJL</sub> and lead to ambient.

D. The static characteristics in Figures 1 to 6,12,14 are obtained using 80μs pulses, duty cycle 0.5% max.

E. These tests are performed with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with T<sub>A</sub>=25°C. The SOA curve provides a single pulse rating.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

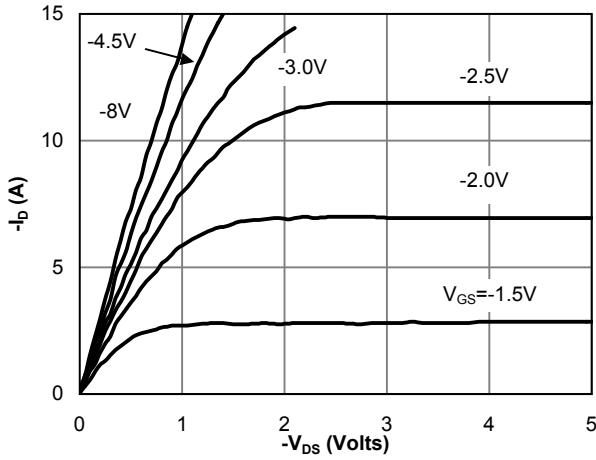


Fig 1: On-Region Characteristics

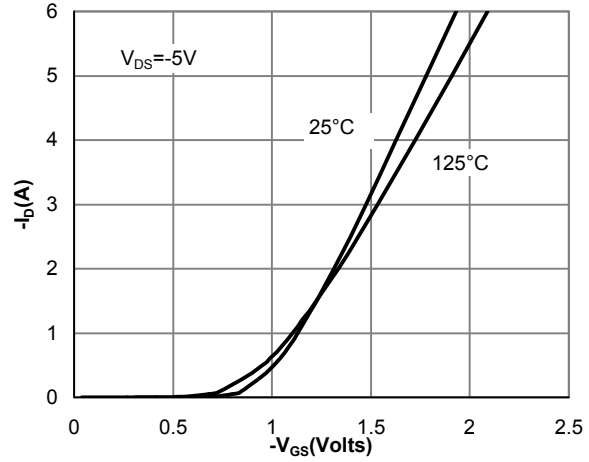


Figure 2: Transfer Characteristics

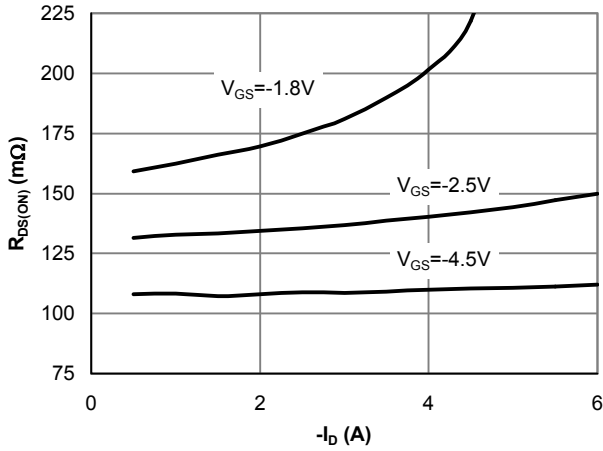


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

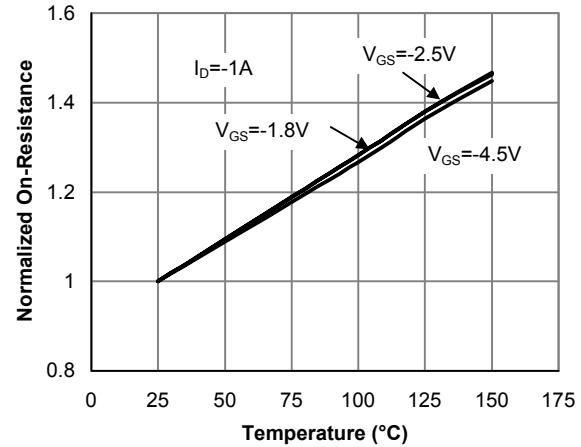


Figure 4: On-Resistance vs. Junction Temperature

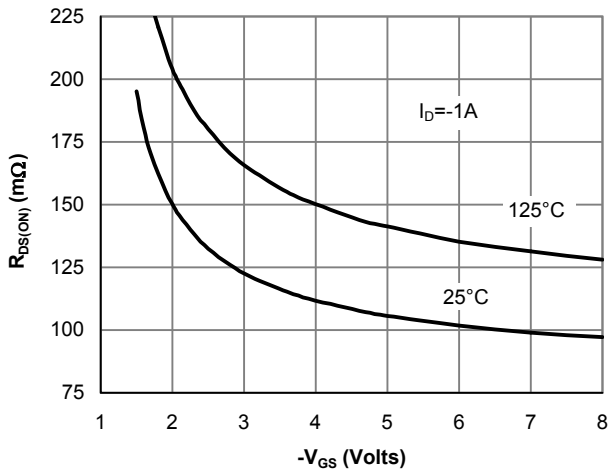


Figure 5: On-Resistance vs. Gate-Source Voltage

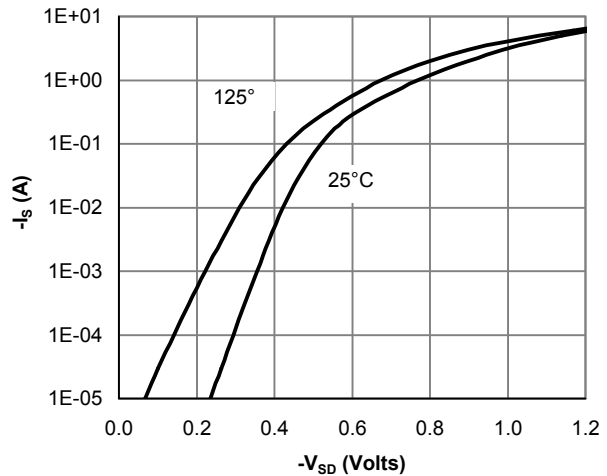


Figure 6: Body-Diode Characteristics

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

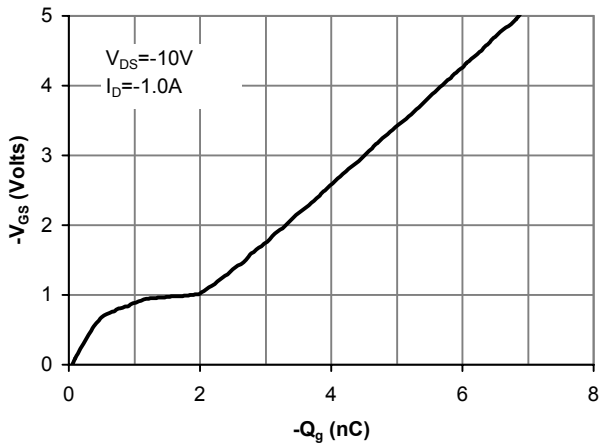


Figure 7: Gate-Charge Characteristics

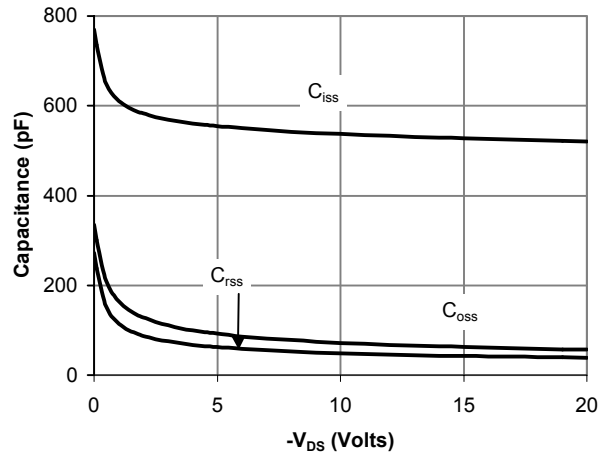


Figure 8: Capacitance Characteristics

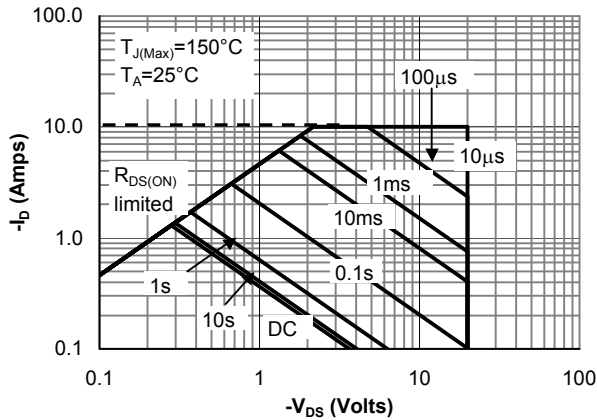


Figure 9: Maximum Forward Biased Safe Operating Area (Note E)

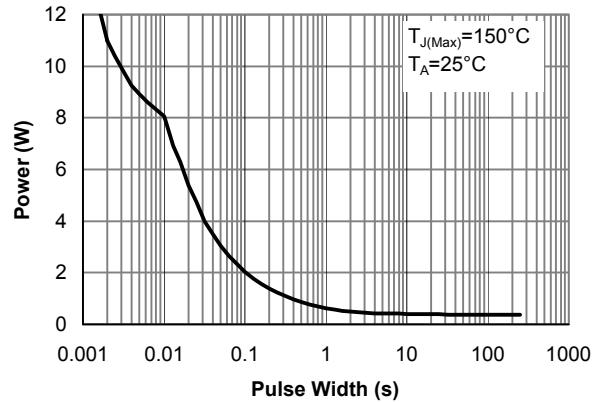


Figure 10: Single Pulse Power Rating Junction-to-Ambient (Note E)

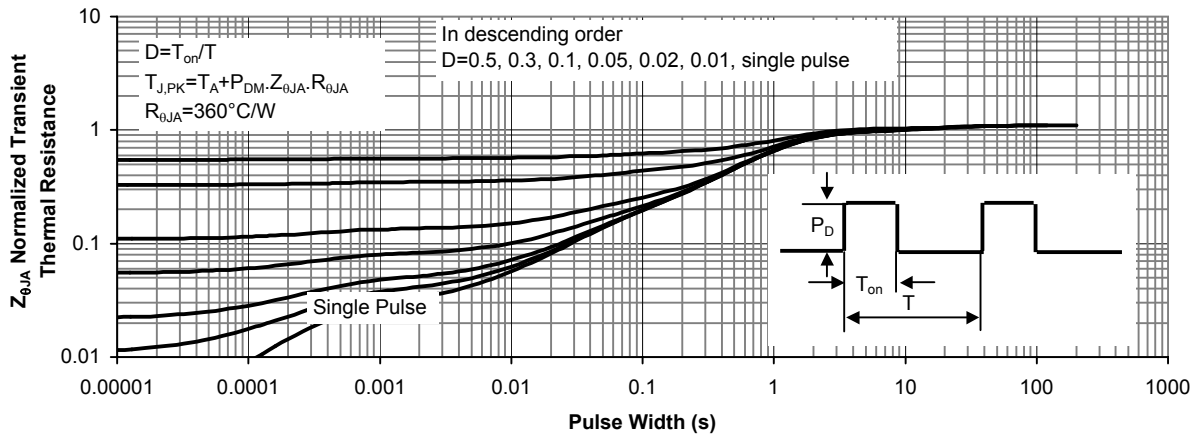
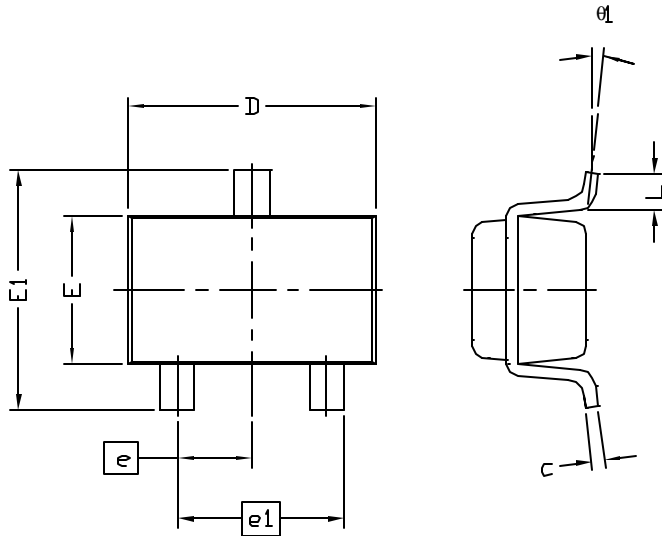
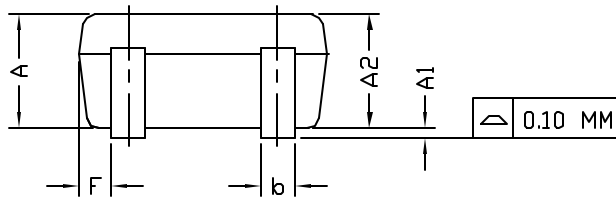


Figure 11: Normalized Maximum Transient Thermal Impedance

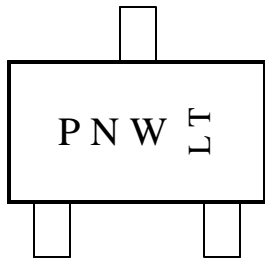


| SYMBOLS    | DIMENSIONS IN MILLIMETERS |      |
|------------|---------------------------|------|
|            | MIN                       | MAX  |
| A          | 0.90                      | 1.10 |
| A1         | 0.00                      | 0.10 |
| A2         | 0.90                      | 1.00 |
| b          | 0.25                      | 0.40 |
| C          | 0.10                      | 0.20 |
| D          | 1.80                      | 2.20 |
| E          | 1.15                      | 1.35 |
| E1         | 2.00                      | 2.20 |
| F          | 0.30                      | 0.40 |
| e          | 0.65 BSC                  |      |
| e1         | 1.30 BSC                  |      |
| L          | 0.10                      | 0.30 |
| $\theta 1$ | 1°                        | 8°   |

- NOTE:
- LEAD FINISH: 150 MICRONS ( 3.8 um) MIN.
  - THICKNESS OF Tin/Lead (SOLDER) PLATED ON LEAD TOLERANCE  $\pm 0.10$  mm (4 mil) UNLESS OTHERWISE SPECIFIED
  - COPLANARITY : 0.10 mm
  - OTHER NAME OF THIS PACKAGE IS CALLED SOT-323



### PACKAGE MARKING DESCRIPTION

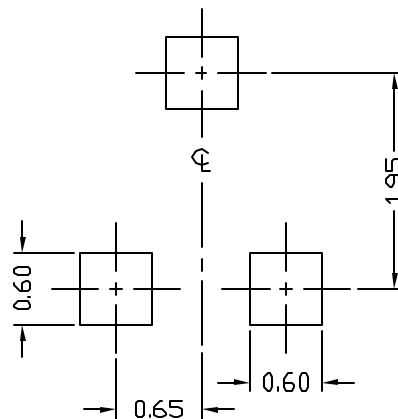


### SC-70 3L PART NO. CODE

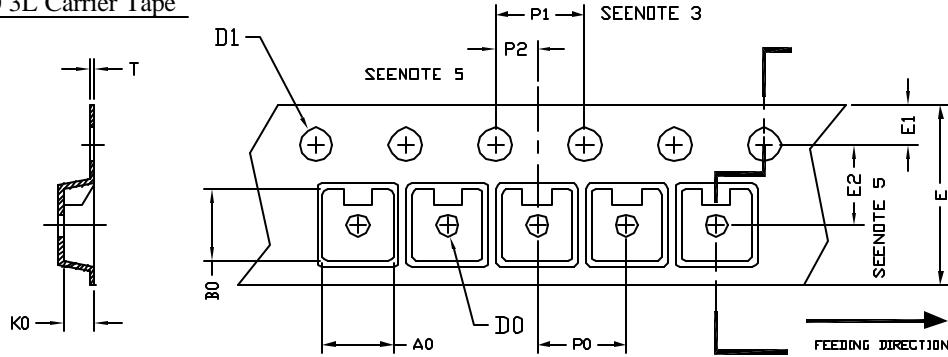
| PART NO. | CODE |
|----------|------|
| AO7407   | 7    |
|          |      |

- NOTE:
- P - PART NUMBER CODE.
  - N - FOUNDRY AND ASSEMBLY LOCATION CODE
  - W - YAER AND WEEK CODE.
  - L T - ASSEMBLY LOT CODE.

### RECOMMENDATION OF LAND PATTERN



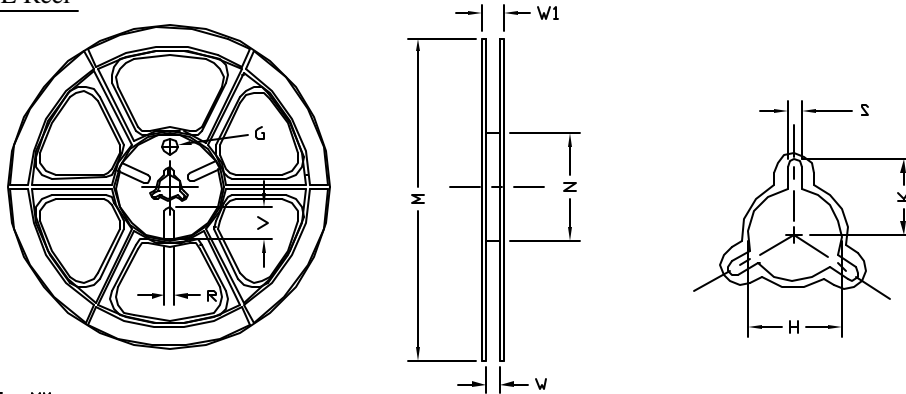
## SC-70 3L Carrier Tape



UNIT: MM

| PACKAGE             | A0            | B0            | K0            | D0          | D1            | E             | E1            | E2            | P0            | P1            | P2            | T             |
|---------------------|---------------|---------------|---------------|-------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|
| SC-70, 3L<br>(B mm) | 2.40<br>±0.10 | 2.40<br>±0.10 | 1.19<br>±0.10 | 1.00<br>MIN | 1.55<br>±0.05 | 8.00<br>±0.30 | 1.75<br>±0.10 | 3.50<br>±0.05 | 4.00<br>±0.10 | 4.00<br>±0.10 | 2.00<br>±0.05 | 0.25<br>±0.05 |

## SC-70 3L Reel



UNIT: MM

| TAPE SIZE | REEL SIZE | M                | N      | W             | W1             | H                        | K     | S             | G     | R    | V     |
|-----------|-----------|------------------|--------|---------------|----------------|--------------------------|-------|---------------|-------|------|-------|
| 8 mm      | φ180      | φ180.00<br>±0.50 | φ60.50 | 9.00<br>±0.30 | 11.40<br>±1.00 | φ13.00<br>+0.50<br>-0.20 | 10.60 | 2.00<br>±0.50 | φ9.00 | 5.00 | 18.00 |

## SC-70 3L Tape

Leader / Trailer  
& Orientation

